

Constitutive modelling of silicon under nano-scale deformation

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Current project on Silicon

Aim of project:

develop a constitutive model for phase transformation of Si

Why a new project?

existing models cannot be applied

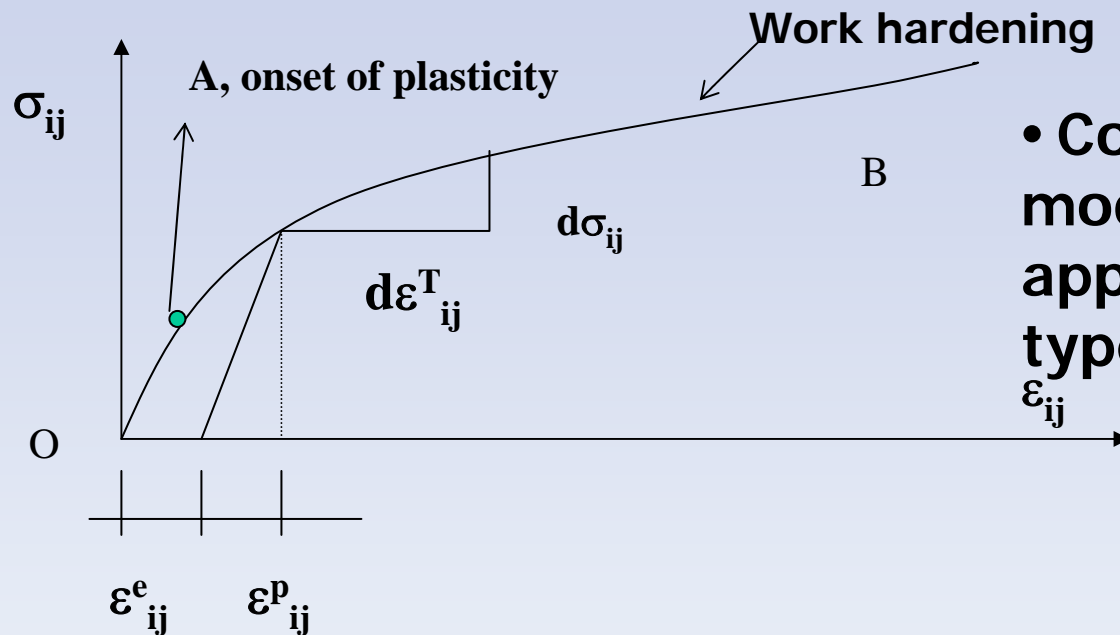
What is a constitutive model?

mathematical formulation of physical behaviour of materials

What does constitutive model consist of?

- prediction of onset of plasticity- due to phase change
- developing of stress/strain relationship

Stress/strain relationship



- Constitutive model is applicable to any type of load

OA- elastic, AB elastic-plastic, $\epsilon^T_{ij} = \epsilon^e_{ij} + \epsilon^p_{ij}$, $d\epsilon_{ij}^p = d\epsilon_{ij}^p, \text{deviatoric} + d\epsilon_{ij}^p, \text{volumetric}$

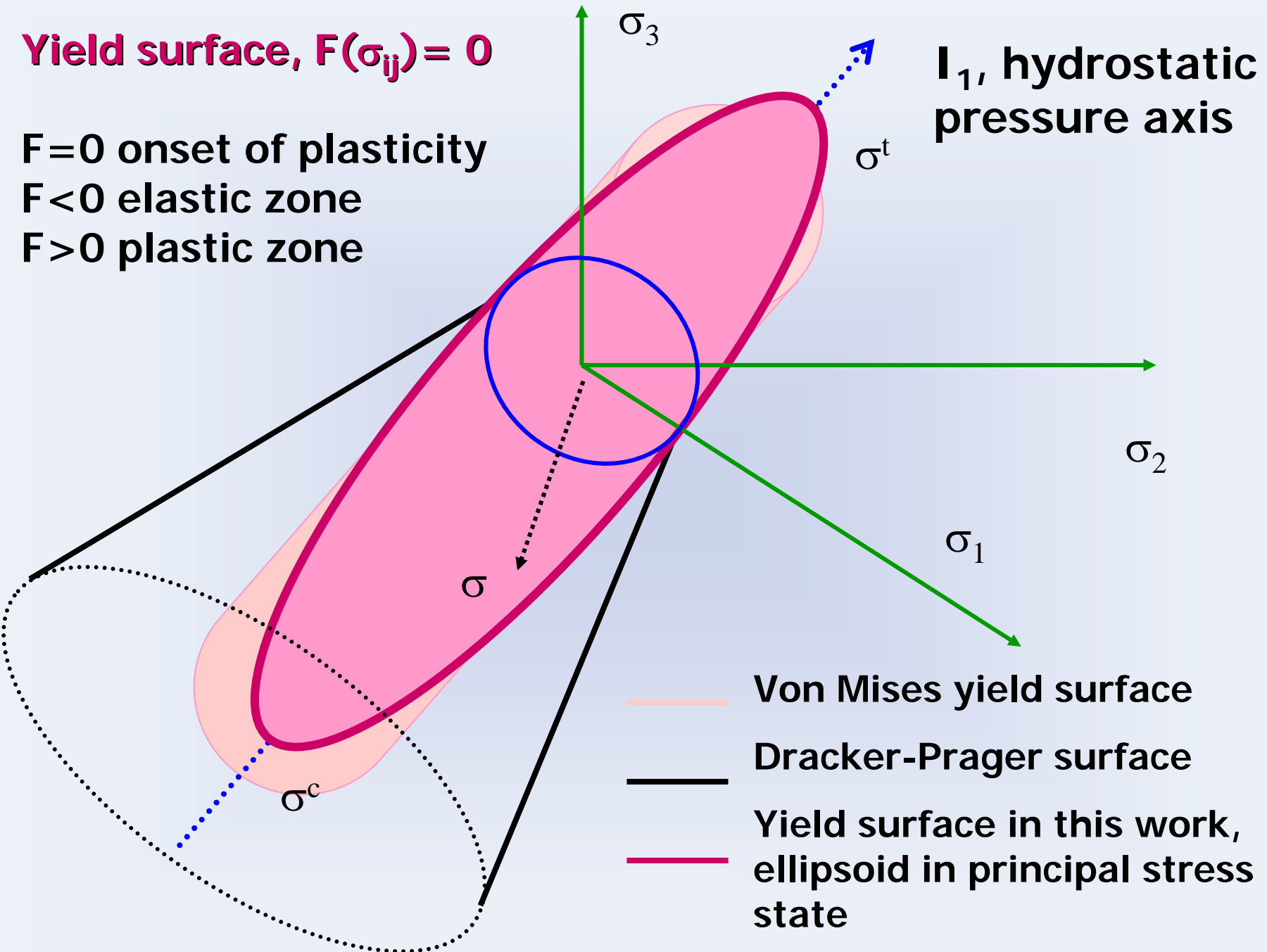
Yield surface, $F(\sigma_{ij}) = 0$

$F=0$ onset of plasticity

$F<0$ elastic zone

$F>0$ plastic zone

**I_1 , hydrostatic
pressure axis**



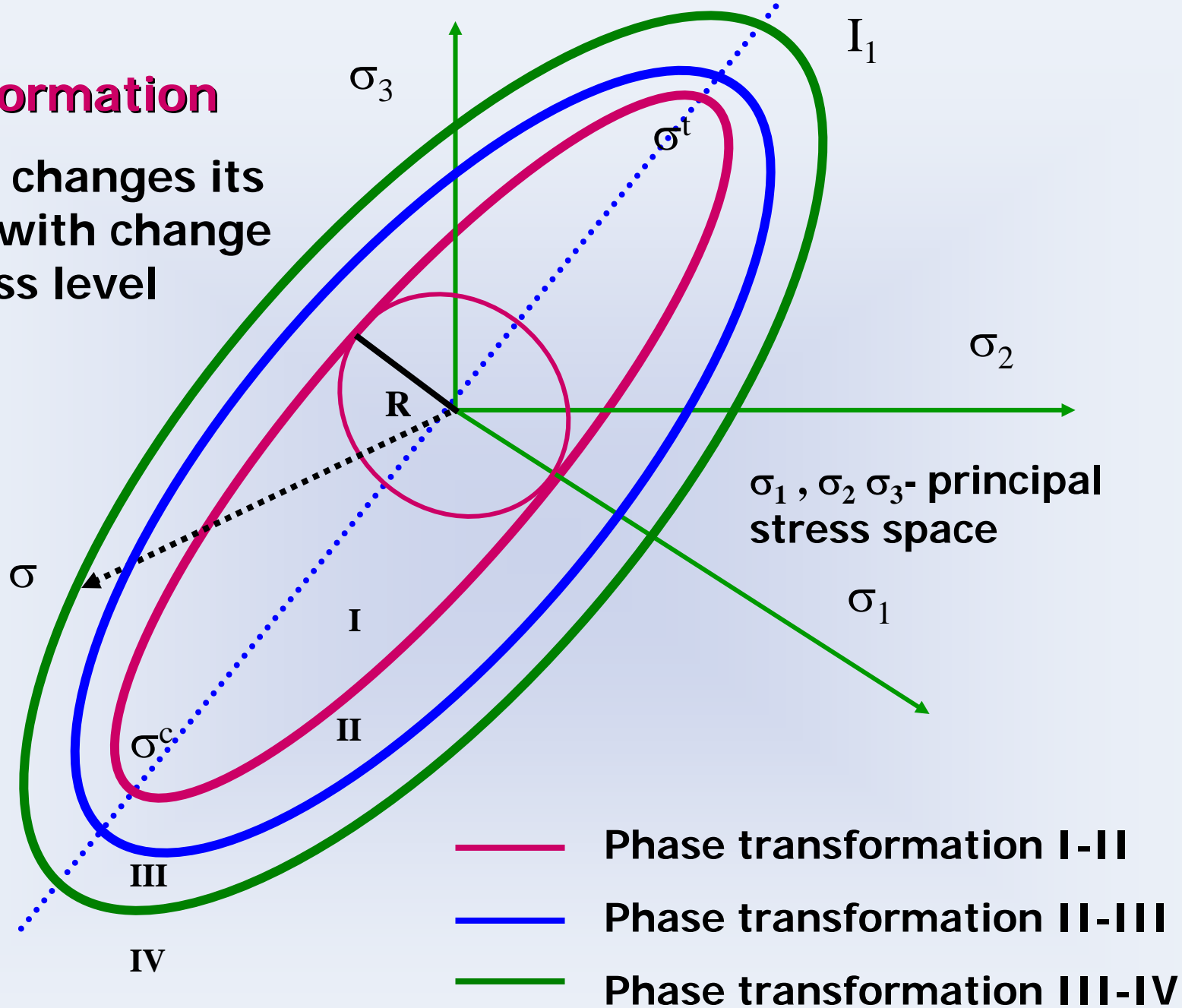
Von Mises yield surface

Drucker-Prager surface

**Yield surface in this work,
ellipsoid in principal stress
state**

Phase transformation

Silicon changes its phase with change in stress level



What do we need to develop?

Incremental stress-strain relation:

$$\{d\sigma\} = [C(\sigma_{mn})] \{d\varepsilon\}, \quad [C] \text{- constitutive matrix is derived}$$

Yield function:

$$F(\sigma, \varepsilon) = (\sigma^{\text{eff}})^2 + 1.5 R^2 I_1^2 / [\sigma_m - (\sigma^t + \sigma^c) / 2]^2 - 1.5 R^2 = 0$$

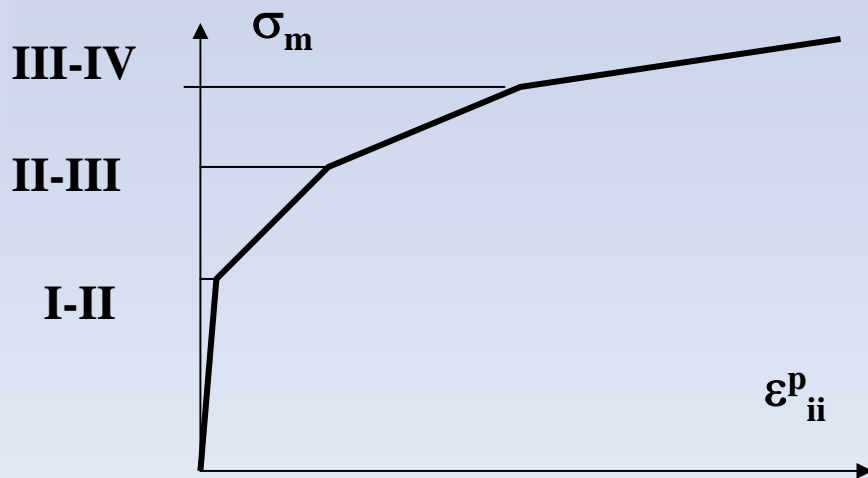
material constants: $E, K; \sigma^t, \sigma^c, R$ for each phase

$F < 0$ elastic, $F > 0$ plastic

Flow rule:

$$d\varepsilon_{ij}^p = \lambda \partial F / \partial \sigma_{ij}, \quad \text{associated normality, isotropic hardening}$$

Hardening is prescribed by hydrostatic pressure tests



- Assumed **multi-linear**
- Given by hydrostatic pressure tests/ molecular dynamics simulations
- Yield surface **uniformly expands** along the semi-axes of ellipsoid

FEA Simulations

ADINA

TIME=10.00

